

# Low Power Dual 8-bit Serial Input DAC

Production Data, April 2001, Rev. 1.0

WM2625

## **FEATURES**

- Dual 8-bit voltage output DAC
- Single supply from 2.7V to 5.5V
- Low supply current
  - 0.8mA typical in slow mode
- 1.8mA typical in fast mode DNL ±0.2 LSB, INL ±0.5 LSB (max)
- Monotonic over temperature
- DSP compatible serial interface •
- Programmable settling time of 1µs or 3µs typical
- High impedance reference input buffer

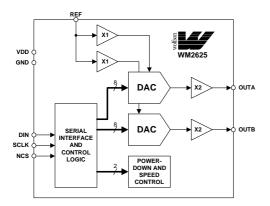
## APPLICATIONS

- **Digital servo control loops**
- Industrial process control
- Battery powered instruments and controls
- Machine and motion control devices
- Digital offset and gain adjustment

## ORDERING INFORMATION

DEVICE	TEMP. RANGE	PACKAGE
WM2625CD	0° to 70°C	8-pin SOIC
WM2625ID	-40° to 85°C	8-pin SOIC

## **BLOCK DIAGRAM**



## DESCRIPTION

The WM2625 is a dual 8-bit voltage output, resistor string digital-to-analogue converter. It can operate with supply voltages between 2.7V and 5.5V and can be powered down under software control. Power down reduces current consumption to 1µA.

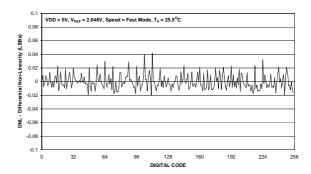
The device has been designed for glueless interface to industry standard microprocessors and DSPs. The WM2625 is programmed with a 16-bit serial word including 4 control bits and 8 data bits.

Excellent performance is delivered with a typical DNL of 0.2LSBs. Monotonicity is guaranteed over the operating temperature range. The settling time of the DAC is programmable to allow for optimisation of speed versus power dissipation. The analogue output is buffered by a rail-to-rail amplifier with a gain of two and a Class AB output stage.

The reference voltage input features a high impedance buffer which eliminates the need to keep the reference source impedance low.

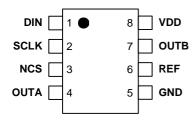
The WM2625 is available in an 8-pin SOIC package. Commercial (0° to 70°C) and Industrial (-40° to  $85^{\circ}$ C) temperature range variants are available.

## **TYPICAL PERFORMANCE**



Production Data Datasheets contain final specifications current on publication date. Supply of products conforms to Wolfson Microelectronics' Terms and conditions.

## **PIN CONFIGURATION**



### **PIN DESCRIPTION**

PIN NO	NAME	TYPE	DESCRIPTION
1	DIN	Digital input	Serial data input
2	SCLK	Digital input	Serial clock input
3	NCS	Digital input	Chip select. This pin is active low.
4	OUTA	Digital input	DAC A analogue voltage output
5	GND	Supply	Ground
6	REF	Analogue input	Voltage reference input
7	OUT	Analogue output	DAC B analogue voltage output
8	VDD	Supply	Positive power supply

## **ABSOLUTE MAXIMUM RATINGS**

Absolute Maximum Ratings are stress ratings only. Permanent damage to the device may be caused by continuously operating at or beyond these limits. Device functional operating limits and guaranteed performance specifications are given under Electrical Characteristics at the test conditions specified.



ESD Sensitive Device. This device is manufactured on a CMOS process. It is therefore generically susceptible to damage from excessive static voltages. Proper ESD precautions must be taken during handling and storage of this device.

CONDITION		MIN	MAX
Supply voltage, VDD to GND			7V
Digital input voltage		-0.3V	VDD + 0.3V
Reference input voltage		-0.3V	VDD + 0.3V
Operating temperature range, T <sub>A</sub>	WM2625CD	0°C	70°C
	WM2625ID	-40°C	85°C
Storage temperature		-65°C	150°C
Soldering lead temperature, 1.6mm (1/ 10 seconds	16 inch) from package body for		260°C

## **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply voltage	VDD		2.7		5.5	V
High-level digital input voltage	VIH	VDD = 2.7V to 5.5V	2			V
Low-level digital input voltage	VIL	VDD = 2.7V to 5.5V			0.8	V
Reference voltage to REF pin	V <sub>REF</sub>	See Note	GND		VDD - 1.5	V
Load resistance	RL		2			kΩ
Load capacitance	CL				100	pF
Serial clock frequency	<b>f</b> <sub>SCLK</sub>				20	MHz
Operating free-air temperature	T <sub>A</sub>	WM2625CD	0		70	°C
		WM2625ID	-40		85	°C

**Note:** Reference input voltages greater than VDD/2 will cause clipping for large DAC codes.

# **ELECTRICAL CHARACTERISTICS**

### **Test Conditions:**

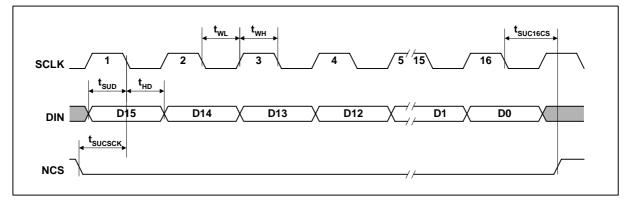
 $R_L = 10k\Omega$ ,  $C_L = 100pF$ . VDD = 5V ±10%,  $V_{REF} = 2.048V$  and VDD = 3V ±10%,  $V_{REF} = 1.024V$  over recommended operating free-air temperature range (unless noted otherwise).

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static DAC Specifications					L.	
Resolution			8			bits
Integral non-linearity	INL	See Note 1		±0.3	±0.5	LSB
Differential non-linearity	DNL	See Note 2		±0.07	±0.2	LSB
Zero code error	ZCE	See Note 3			±12	mV
Gain error	GE	See Note 4			±0.5	% FSF
D.C. power supply rejection ratio	D.C. PSRR	See Note 5		-65		mV/V
Zero code error temperature coefficient		See Note 6		10		ppm/°0
Gain error temperature coefficient		See Note 6		10		ppm/°0
DAC Output Specifications		L	1			J
Output voltage range			0		VDD - 0.4	V
Output load regulation		2kΩ to 10kΩ load See Note 7			0.29	% FS
Power Supplies		No load, DAC value = 128,			L.	
A	i .	all digital inputs 0V or VDD				
Active supply current	I <sub>DD</sub>	Slow Mode		0.8	1	mA
Device device events	-	Fast Mode		1.8	2.3	mA
Power down supply current		See Note 8		1	3	μA
Dynamic DAC Specifications						1
Slew rate	SR	DAC output 10%-90% Slow		0.5		V/µs
		Fast		3		V/μs
		See Note 9				
Full-scale settling time	ts	DAC output 10%-90%			10	
		Slow Fast		3	10 3	μs μs
		See Note 10			Ŭ	μο
Glitch energy		$\label{eq:DIN} \begin{array}{l} DIN = 0 \text{ to } 1, \ f_{CLK} = 100 \text{kHz}, \\ NCS = VDD \end{array}$		5		nV-s
Signal to noise ratio	SNR	f <sub>s</sub> = 102kSPS,	52	54		dB
Signal to noise and distortion ratio	SINAD	$f_{OUT} = 1 kHz,$	48	49		dB
Total harmonic distortion	THD	See Note 11		-50	-48	dB
Spurious free dynamic range	SFDR		48	50		dB
Reference						
Reference input resistance	R <sub>REFIN</sub>			10		MΩ
Reference input capacitance	C <sub>REFIN</sub>			5		pF
Reference feedthrough		V <sub>REF</sub> = 1V <sub>PP</sub> at 1kHz + 1.024V dc, DAC code 0		-80		dB
Reference input bandwidth		V <sub>REF</sub> = 0.2V <sub>PP</sub> + 1.024V dc Slow Fast		0.525 1.3		MHz MHz
Digital Inputs	<u> </u>	i dəl		1.3		
High level input current	IIH	Input voltage = VDD	-1		1	μA
Low level input current		Input voltage = 0V	-1		1	μA
Input capacitance				8	· ·	pF

### WM2625

Notes:

- 1. Integral non-linearity (INL) is the maximum deviation of the output from the line between zero and full scale (excluding the effects of zero code and full scale errors).
- Differential non-linearity (DNL) is the difference between the measured and ideal 1LSB amplitude change of any adjacent two codes. A guarantee of monotonicity means the output voltage always changes in the same direction (or remains constant) as the digital input code.
- 3. Zero code error is the voltage output when the DAC input code is zero.
- 4. Gain error is the deviation from the ideal full-scale output excluding the effects of zero code error.
- 5. **Power supply rejection ratio** is measured by varying VDD from 4.5V to 5.5V and measuring the proportion of this signal imposed on the zero code error and the gain error.
- 6. Zero code error and Gain error temperature coefficients are normalised to full-scale voltage.
- 7. Output load regulation is the difference between the output voltage at full scale with a  $10k\Omega$  load and  $2k\Omega$  load. It is expressed as a percentage of the full scale output voltage with a  $10k\Omega$  load.
- 8.  $I_{DD}$  is measured while continuously writing code 128 to the DAC. For  $V_{IH} < VDD 0.7V$  and  $V_{IL} > 0.7V$  supply current will increase.
- 9. Slew rate results are for the lower value of the rising and falling edge slew rates
- 10. Settling time is the time taken for the signal to settle to within 0.5LSB of the final measured value for both rising and falling edges. Limits are ensured by design and characterisation, but are not production tested.
- 11. SNR, SNRD, THD and SPFDR are measured on a synthesised sine wave at frequency  $f_{OUT}$  generated with a sampling frequency  $f_{s.}$



## SERIAL INTERFACE

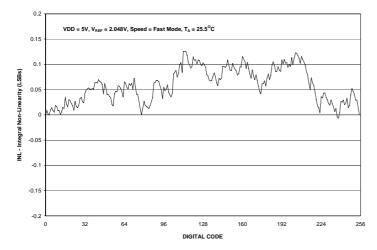
Figure 1 Timing Diagram

#### Test Conditions:

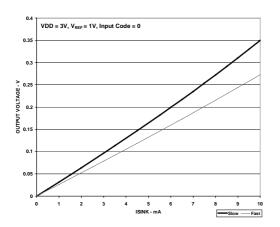
 $R_L$  = 10k $\Omega$ ,  $C_L$  = 100pF. VDD = 5V ± 10%,  $V_{REF}$  = 2.048V and VDD = 3V ± 10%,  $V_{REF}$  = 1.024V over recommended operating free-air temperature range (unless noted otherwise).

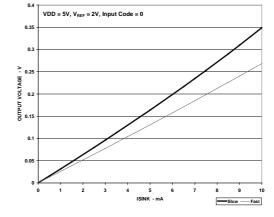
SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
tsucsck	Setup time, NCS low before first falling SCLK edge	10			ns
t <sub>SUC16CS</sub>	Setup time, 16 <sup>th</sup> falling SCLK edge (when data bit D0 is sampled) before NCS rising edge.	10			ns
t <sub>WH</sub>	Pulse duration, SCLK high.	25			ns
t <sub>WL</sub>	Pulse duration, SCLK low.	25			ns
t <sub>SUD</sub>	Setup time, data ready before SCLK falling edge.	10			ns
t <sub>HD</sub>	Hold time, data held valid after SCLK falling edge.	10			ns

## **TYPICAL PERFORMANCE GRAPHS**











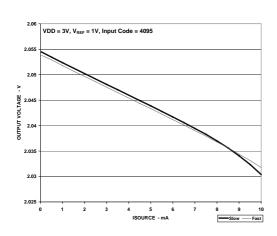


Figure 4 Sink Current VDD = 5V

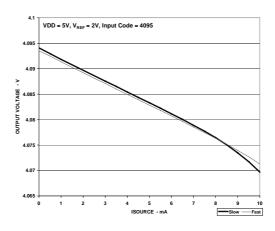


Figure 5 Source Current VDD = 3V



## **DEVICE DESCRIPTION**

## **GENERAL FUNCTION**

The WM2625 is a dual 8-bit, voltage output DAC operating from a single supply. It uses a resistor string network buffered with an op amp to convert 8-bit digital data to analogue voltage levels (see Block Diagram). The output voltage is determined by the reference input voltage and the input code according to the following relationship:

$$V_{out} = 2 \Big( V_{REFIN} \Big) \frac{CODE}{256}$$

INF	PUT	OUTPUT
1111	1111	$2(V_{REF})\frac{255}{256}$
		:
1000	0001	$2\left(V_{REF}\right)\frac{129}{256}$
1000	0000	$2\left(V_{REF}\right)\frac{128}{256}=V_{REF}$
0111	1111	$2\left(V_{REF}\right)\frac{127}{256}$
		:
0000	0001	$2(V_{REF})\frac{1}{256}$
0000	0000	0V

Table 1 Binary Code Table (0V to 2V<sub>REF</sub> Output), Gain = 2

### POWER ON RESET

An internal power-on-reset circuit resets the DAC register to all 0s on power-up.

### **BUFFER AMPLIFIER**

The output buffer has a near rail-to-rail output with short circuit protection and can reliably drive a  $2k\Omega$  load with a 100pF load capacitance.

### **EXTERNAL REFERENCE**

The reference voltage input is buffered which makes the DAC input resistance independent of code. The REF pin has an input resistance of  $10M\Omega$  and an input capacitance of typically 5pF. The reference voltage determines the DAC full-scale output.

### SERIAL INTERFACE

Before writing any data to the WM2625, the interface must be enabled by setting NCS to low. Incoming data on DIN (starting with the MSB) is then shifted bit-per-bit into the internal register on the falling edges of SCLK. From there data is loaded into the target latch after 16 bits have been transferred, or when NCS rises. Three internal latches can be addressed: DAC A, DAC B, or the buffer latch. This makes it possible to update both DACs simultaneously or to update one independently of the other (see 'Addressing the Buffer and DAC Latches', below).

### SERIAL CLOCK AND UPDATE RATE

Figure 1 shows the device timing. The maximum serial rate is:

$$f_{SCLK \max} = \frac{1}{t_{WH \min} + t_{WL \min}} = 20MHz$$

Production Data

Since a data word contains 16 bits, the sample rate for one channel is limited to

$$f_{s\max} = \frac{1}{16 \times (t_{WH\min} + t_{WL\min})} = 1.25 MHz$$

For full two-channel operation, where two data words need to be transmitted per sample, this figure is halved to 625kHz. However, the DAC settling time to 8-bit accuracy limits the response time of the analogue output for large input step transitions.

### SOFTWARE CONFIGURATION OPTIONS

Table 2 shows the composition of a 16-bit data word. D11-D4 contains the 8-bit data word, and D14-D13 hold the programmable options. Bits D15 and D12 are used for addressing the different latches. D3 to D0 are unused and should be set to ZERO.

							D5	D4				D0
R1 SPD PWR R0 New DAC value (8 bits) 0 0	R1 SPD PWR	R R0	New D	)AC va	alue (8	bits)			0	0	0	0

Table 2 Register Map

#### **PROGRAMMABLE CONVERTER SPEED**

SPD (Bit 14) allows for software control of the converter speed. A ONE selects the fast mode, where typical settling time to within  $\pm 0.5$ LSB of the final value is 1µs. a ZERO puts the device into the slow mode, where typical settling time is 3µs.

#### **PROGRAMMABLE POWER DOWN**

The power down function is controlled by PWR (Bit 13). A ZERO configures the device as active, or fully powered up, a ONE sets the device into power down mode. When the power down function is released the device reverts to the DAC code set prior to power down.

### ADDRESSING THE BUFFER AND DAC LATCHES

Data received on the serial interface is routed according to the values of bits R1 and R0, as shown in Table 3  $\,$ 

R1	R0	REGISTER
(BIT D15)	(BIT D12)	
0	0	Write data to DAC B and buffer
0	1	Write data to buffer
1	0	Write data to DAC A and update DAC B with buffer content
1	1	Reserved

#### Table 3 Latch Addressing

To update both DACs simultaneously, the data intended for DAC B should first be stored in the buffer. Subsequently, writing data to DAC A will automatically update the DAC B latch from the buffer, so that the analogue output of both DACs will change at the same time.

When updating the two channels independently, all data written to the DAC B latch (R1 and R0 set to ZERO) is also copied to the buffer. Thus the automatic update of DAC B when writing to DAC A latch (R1=1, R0=0) does not change the DAC B data. Data should not be written only to the buffer when operating in this mode.

### **EXAMPLES OF OPERATION**

#### Simultaneous operation, slow mode:

1. Write data for DAC B to buffer

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	1			Nev	N DAC	B val	ue			0	0	0	0

2. Write new DAC A value and update DAC B from buffer simultaneously

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
1	0	0	0			Nev	w DAC	A valu	ue			0	0	0	0

#### Independent operation, fast mode:

Set DAC B output (fast mode):

D15 D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0 1	0	0				N DAC	- ·	-			0	0	0	0

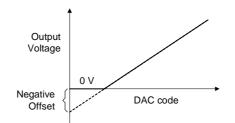
#### Set DAC A output (fast mode):

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
1	1	0	0	New DAC A value					0	0	0	0			

## **APPLICATIONS INFORMATION**

### LINEARITY, OFFSET, AND GAIN ERROR

Amplifiers operating from a single supply can have positive or negative voltage offsets. With a positive offset, the output voltage changes on the first code transition. However, if the offset is negative, the output voltage may not change with the first code, depending on the magnitude of the offset voltage. This is because with the most negative supply rail being ground, any attempt to drive the output amplifier below ground will clamp the output at 0 V. The output voltage then remains at zero until the input code is sufficiently high to overcome the negative offset voltage, resulting in the transfer function shown in Figure 7.



#### Figure 7 Effect of Negative Offset

This offset error, not the linearity error, produces the breakpoint. The transfer function would follow the dotted line if the output buffer could drive below the ground rail.

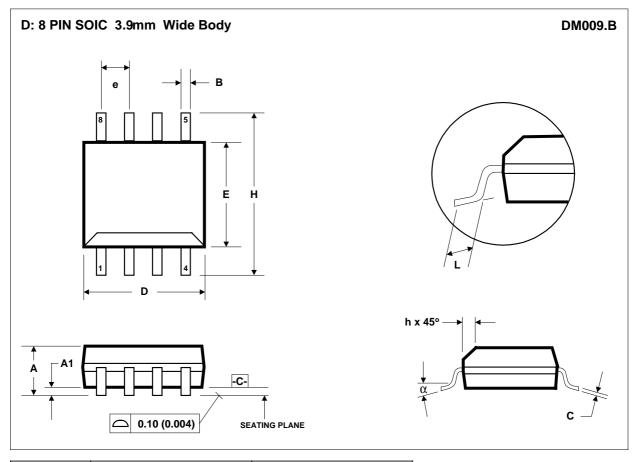
DAC linearity is measured between zero-input code (all input bits at 0) and full-scale code (all inputs at 1), disregarding offset and full-scale errors. However, due to the breakpoint in the transfer function, single supply operation does not allow for adjustment when the offset is negative. In such cases, the linearity is therefore measured between full-scale and the lowest code that produces a positive (non-zero) output voltage.

### POWER SUPPLY DECOUPLING AND GROUNDING

Printed circuit boards with separate analogue and digital ground planes deliver the best system performance. The two ground planes should be connected together at the low impedance power supply source. Ground currents should be managed so as to minimise voltage drops across the ground planes.

A  $0.1\mu$ F decoupling capacitor should be connected between the positive supply and ground pins of the DAC, with short leads as close as possible to the device. Use of ferrite beads may further isolate the system analogue supply from the digital supply.

## **PACKAGE DIMENSIONS**



	Dimer	nsions	Dimensions (Inches)				
Symbols	(m	m)					
	MIN	MAX	MIN	MAX			
Α	1.35	1.75	0.0532	0.0688			
<b>A</b> <sub>1</sub>	0.10	0.25	0.0040	0.0098			
В	0.33	0.51	0.0130	0.0200			
С	0.19	0.25	0.0075	0.0098			
D	4.80	5.00	0.1890	0.1968			
е	1.27	BSC	0.050 BSC				
E	3.80	4.00	0.1497	0.1574			
h	0.25	0.50	0.0099	0.0196			
Н	5.80	6.20	0.2284	0.2440			
L	0.40	1.27	0.0160	0.0500			
α	0°	8°	0°	8°			
		-	· ·	•			
REF:	JEDEC.95, MS-012						

NOTES: A. ALL LINEAR DIMENSIONS ARE IN MILLIMETERS (INCHES). B. THIS DRAWING IS SUBJECT TO CHANGE WITHOUT NOTICE. C. BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSION, NOT TO EXCEED 0.25MM (0.010IN). D. MEETS JEDEC.95 MS-012, VARIATION = AA. REFER TO THIS SPECIFICATION FOR FURTHER DETAILS.